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## Irf640 makes 12v inverter

[IRF640 Datasheet \(PDF\)](#) - International Rectifier ... [IRF640 Datasheet \(HTML\)](#) - International Rectifier [IRF640 Product details](#) Description Third Generation HEXFETs from International ...

**DESCRIPTION** Third generation power MOSFETs from Vishay provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and ...

With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims ...

IRF640N is a N-channel power MOSFETs with VDS max: 200 V, RDS (on) max: 150 mOhm, Package: TO-220, Technology: IR MOSFET(TM), ID max: 18 A

Web: <https://stanfashion.pl>

